

Switchmode Power Rectifiers

... Designed for use in switching power supplies, inverters and as free wheeling diodes. These state-of-the-art devices have the following features:

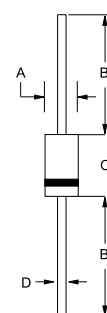
- * High Surge Capacity
- * Low Power Loss, High efficiency
- * Glass Passivated chip junctions
- * 150 °C Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction
- * Low Forward Voltage , High Current Capability
- * Ultrafast 35 & 50 Nanosecond Recovery Time
- * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O

**ULTRA FAST
RECTIFIERS**

**1.0 AMPERES
50 -- 400 VOLTS**



DO-41



DIM	MILLIMETERS	
	MIN	MAX
A	2.00	2.70
B	25.40	---
C	4.10	5.20
D	0.70	0.90

CASE---
Transfer molded
plastic

POLARITY---
Cathode indicated
polarity band

MAXIMUM RATINGS

Characteristic	Symbol	SF						Unit
		11	12	13	14	15	16	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	50	100	150	200	300	400	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	105	140	210	280	V
Average Rectifier Forward Current	I_o	1.0						A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware,single phase,60Hz)	I_{FSM}	30				25		A
Operating and Storage Junction Temperature Range	T_J , T_{stg}	- 65 to + 150						°C

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	SF						Unit
		11	12	13	14	15	16	
Maximum Instantaneous Forward Voltage (I_F =1.0 Amp, T_C = 25 °C)	V_F	0.95				1.30		V
Maximum Instantaneous Reverse Current (Rated DC Voltage, T_C = 25 °C) (Rated DC Voltage, T_C = 125 °C)	I_R	5.0 50						uA
Reverse Recovery Time (I_F = 0.5 A, I_R =1.0 , I_{rr} =0.25 A)	T_{rr}	35				50		ns
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	C_P	25				20		pF

SF11 Thru SF16

FIG-1 TYPICAL FORWARD CHARACTERISTICS

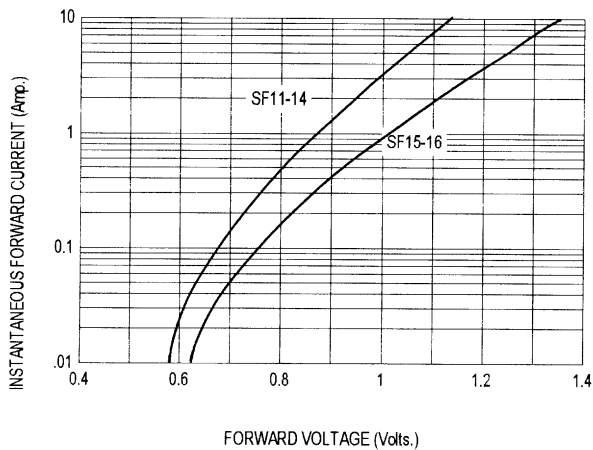


FIG-2 TYPICAL REVERSE CHARACTERISTICS

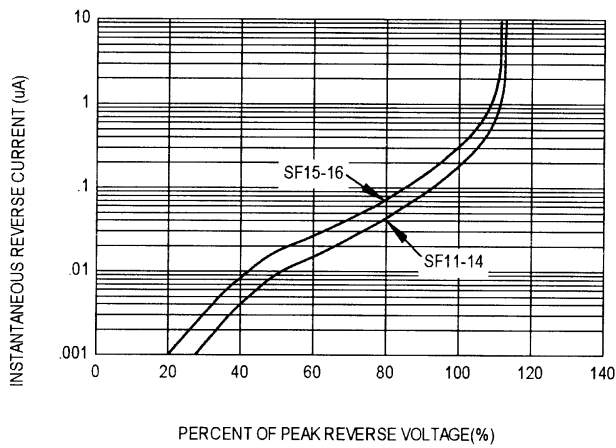


FIG-3 FORWARD CURRENT DERATING CURVE

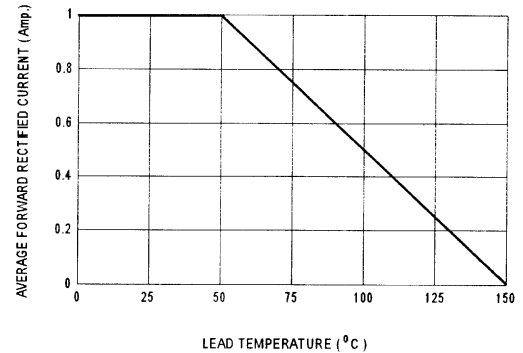


FIG-4 TYPICAL JUNCTION CAPACITANCE

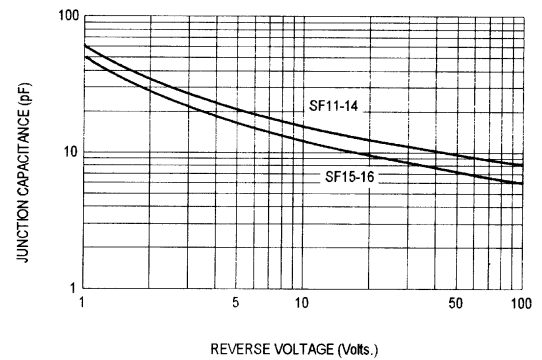
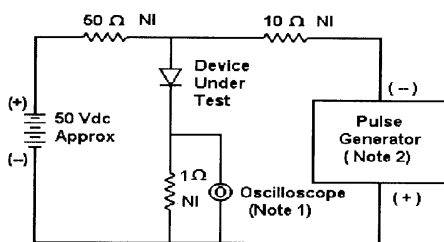
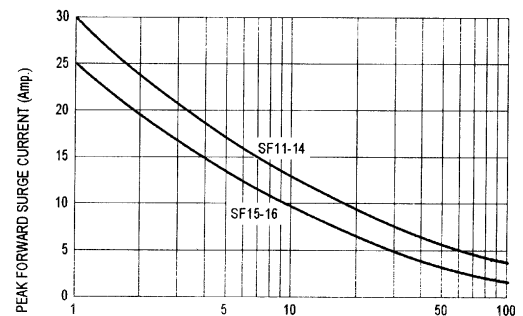
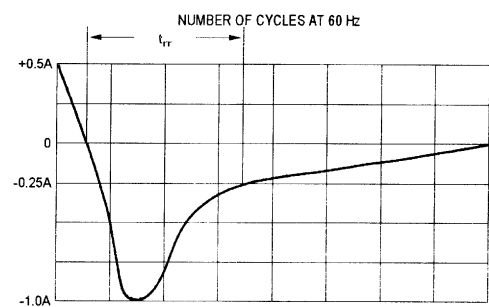


FIG-5 PEAK FORWARD SURGE CURRENT



- Notes:
 1. Rise Time = 7 ns max. Input Impedance = 1 M Ω , 22 pF
 2. Rise Time = 10 ns max. Input Impedance = 50 Ω



Set time base for 10/20 ns/cm

Fig-6 Reverse Recovery Time Characteristic and Test Circuit Diagram